

RF AMPLIFIER

MODEL *TM3110PM*

Available as: TM3110PM, 4 Pin TO-8 (T4)
 TN3110PM, 4 Pin Surface Mount (SM3)
 BX3110PM, Connectorized Housing (H1)

Features

- Superior Phase Noise Performance
- High Output Power: +30 dBm Typical
- Operating Temp. -55 °C to +85 °C
- Environmental Screening Available

Typical Intermodulation Performance at 25 °C

Second Order Harmonic Intercept Point +66 dBm (Typ.)
 Second Order Two Tone Intercept Point +63 dBm (Typ.)
 Third Order Two Tone Intercept Point +45 dBm (Typ.)

Absolute Maximum (No Damage) Ratings

Ambient Operating Temperature -55°C to +100 °C
 Storage Temperature -62°C to +125 °C
 Case Temperature +125 °C
 DC Voltage +17 Volts
 Continuous RF Input Power +15 dBm
 Short Term RF Input Power 100 mW (1 Minute Max.)
 Maximum Peak Power 0.2 Watt (3 µsec Max.)
 Total Theta jc (TN3110PM).....+41°C/Watt
 Junction Temp Rise Above Case (TN3110PM)..... 36°C

Specifications

CHARACTERISTIC	TYPICAL Ta= 25 °C	MIN/MAX Ta = -55 °C to +85 °C
Frequency (MHz)	10 - 200 MHz	10 - 200 MHz
Gain (dB)	15.5	15 Min.
Power @ 1 dB Comp. (dBm)	+30	+29 Min.
Reverse Isolation (dB)	-17	-16 Max.
VSWR In	1.8:1	2.0:1 Max.
VSWR Out	1.8:1	2.0:1 Max.
Noise Figure (dB)	3.5	4.5 Max.
Power Vdc	+15	+15
Power mA	240	250 Max.

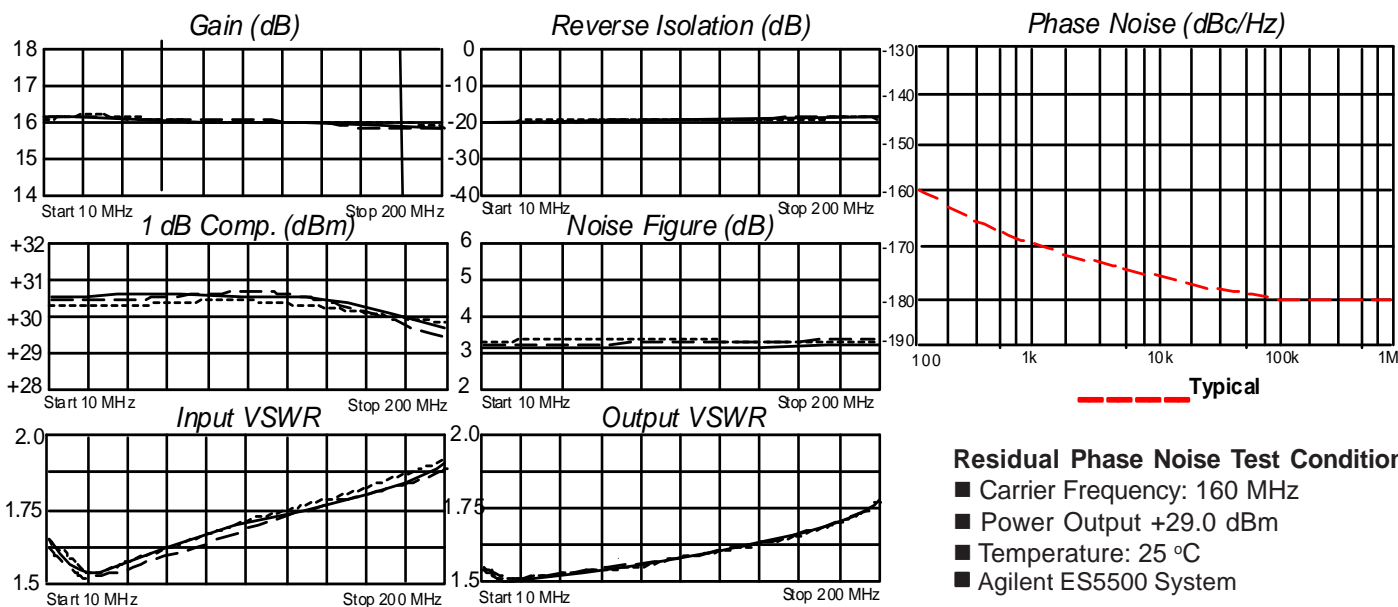
Frequency	Typical	Guarantee
100 Hz	-160	-155
1 kHz	-170	-165
10 kHz	-175	-170
100 kHz	-180	-175
1 MHz	-180	-175

Note: Care should always be taken to effectively ground the case of each unit.
 *Note: Phase Noise Performance typically tested at midband. Bandedge performance may vary.

Guaranteed @ 25 °C (160 MHz) Phase Noise Performance (dBc/Hz)*

Note: Unit requires a 50 ohm termination at all times.

Typical Performance Data



Residual Phase Noise Test Conditions:

- Carrier Frequency: 160 MHz
- Power Output +29.0 dBm
- Temperature: 25 °C
- Agilent ES5500 System

Legend ——— +25 °C - - - +85 °C ····· -55 °C

